



### 60V P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

-300mA

#### **Features**

- RDS(ON), VGS@-10V, ID@-500mA<4Ω
- RDS(ON), VGS@-4.5V, ID@-200mA<6Ω
- RDS(ON), VGS@-2.5V, ID@-50mA<13Ω</li>
- Advanced Trench Process Technology
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

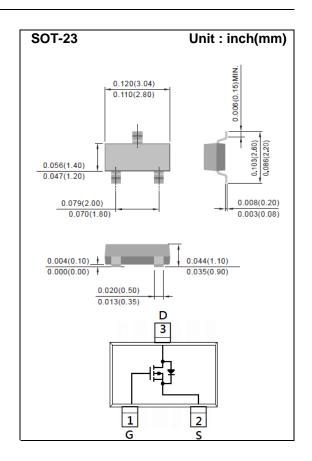
#### **Mechanical Data**

Case: SOT-23 Package

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A39



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-60	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	-300	mA
Pulsed Drain Current		I <sub>DM</sub>	-1000	mA
Power Dissipation	T <sub>A</sub> =25°C	$P_{D}$	500	mW
	Derate above 25°C		4	mW/°C
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	250	°C/W





# Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static (Note 1)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-1.0	-1.5	-2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-500mA	-	2.4	4	Ω
		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-200mA	-	2.65	6	
		V <sub>GS</sub> =-2.5V,I <sub>D</sub> =-50mA	-	4.5	13	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-48V,V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 4)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-25V, I <sub>D</sub> =-100mA, V <sub>GS</sub> =-4.5V	-	1.1	-	nC
Gate-Source Charge	$Q_gs$		-	0.3	-	
Gate-Drain Charge	$Q_gd$		-	0.2	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	51	-	pF ns
Output Capacitance	Coss		-	15	-	
Reverse Transfer Capacitance	Crss	I=1.0IVIDZ	-	2.2	-	
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =-25V, $I_{D}$ =-100mA, $V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	4.8	-	
Turn-On Rise Time	tr		-	19	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	52	-	
Turn-Off Fall Time	tf		-	32	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	-300	mA
Diode Forward Current	I <sub>S</sub>					
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-500mA, V <sub>GS</sub> =0V	-	-0.95	-1.3	V

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
- 4. Guaranteed by design, not subject to production testing





#### **TYPICAL CHARACTERISTIC CURVES**

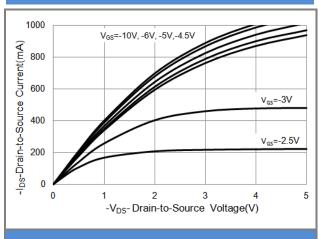
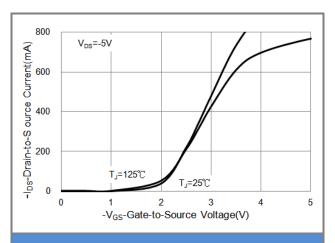


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

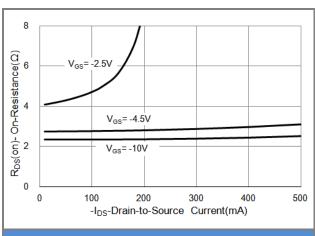


Fig.3 On-Resistance vs. Drain Current

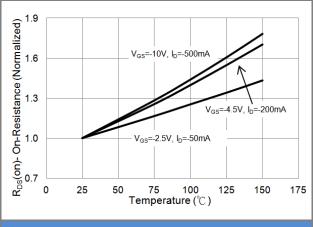


Fig.4 On-Resistance vs. Junction temperature

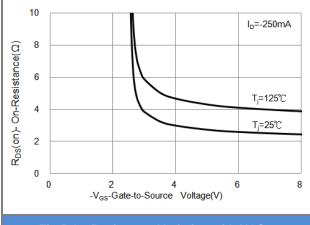


Fig.5 On-Resistance Variation with VGS.

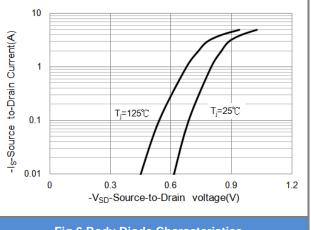


Fig.6 Body Diode Characteristics





### **TYPICAL CHARACTERISTIC CURVES**

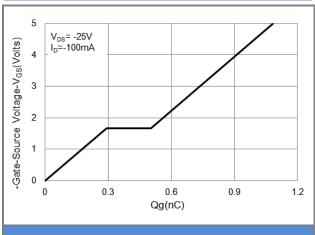


Fig.7 Gate-Charge Characteristics

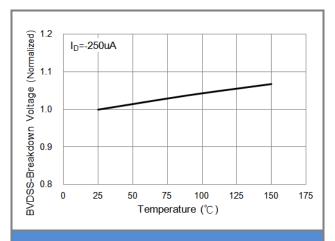


Fig.8 Breakdown Voltage Variation vs. Temperature

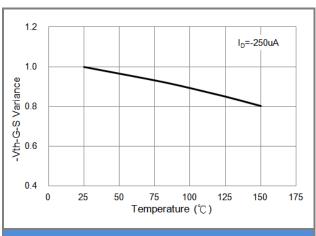


Fig.9 Threshold Voltage Variation with Temperature.

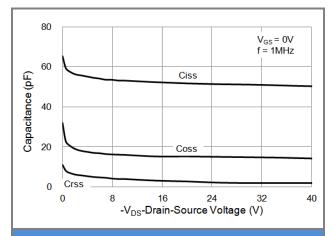


Fig.10 Capacitance vs. Drain-Source Voltage.

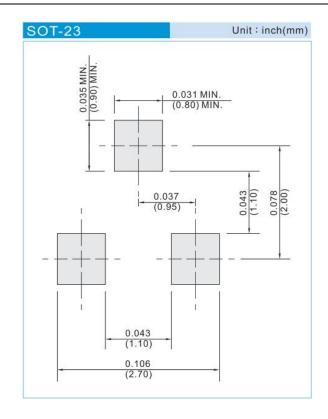




### PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJA3439_R1_00001	SOT-23	3K pcs / 7" reel	A39	Halogen free
PJA3439_R2_00001	SOT-23	12K pcs / 13" reel	A39	Halogen free

## **MOUNTING PAD LAYOUT**







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